



INTERNATIONAL ATOMIC ENERGY AGENCY  
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION  
**INTERNATIONAL CENTRE FOR THEORETICAL PHYSICS**  
I.C.T.P., P.O. BOX 586, 34100 TRIESTE, ITALY, CABLE: CENTRATOM TRIESTE



**SMR. 758 - 34**

**SPRING COLLEGE IN CONDENSED MATTER  
ON QUANTUM PHASES  
(3 May - 10 June 1994)**

=====

**SUPERCONDUCTOR - INSULATOR TRANSITION IN  
 $\text{InO}_x$**

**Mikko PAALANEN**  
Department of Physics  
University of Jyväskylä  
Jyväskylä, Finland

=====

These are preliminary lecture notes, intended only for distribution to participants.

=====

# SUPERCONDUCTOR-INSULATOR TRANSITION IN

InO<sub>x</sub>

Mikko Paalanen AT&T Bell Laboratories

and

Univ. of Jyväskylä 1992→

A.F. HEBARD

R.R. RUEL

M.P.A. FISHER

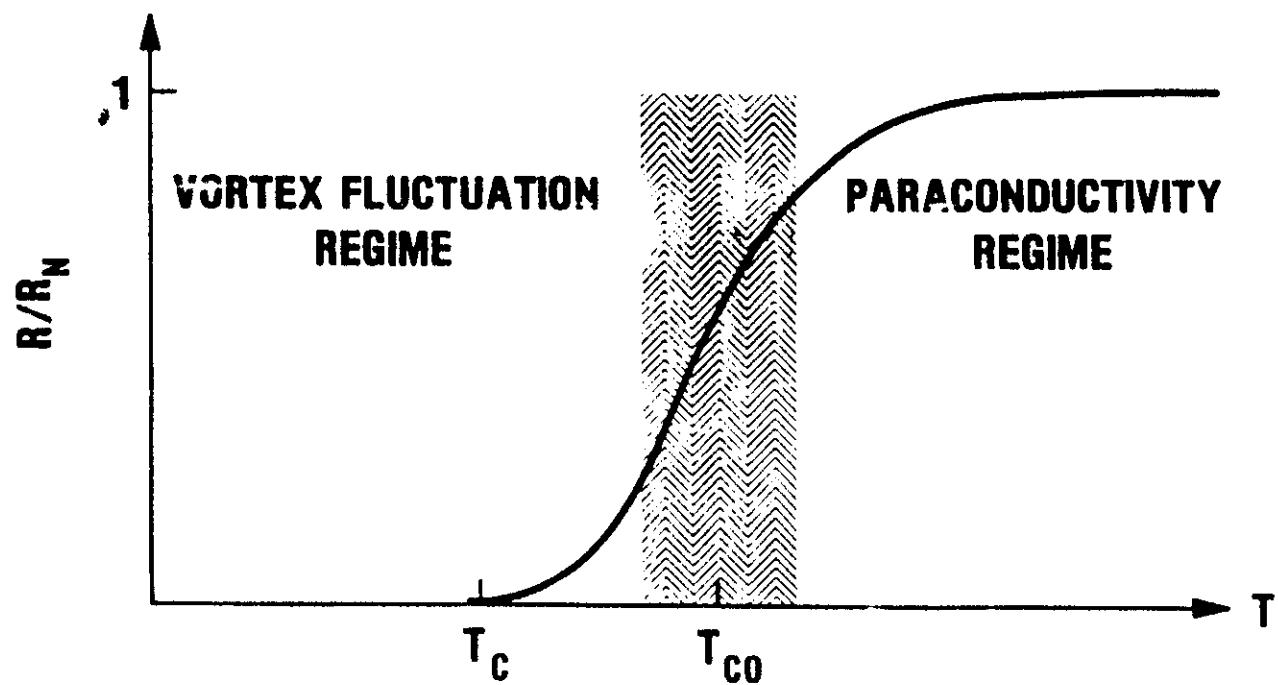
A.T. FIORY

S. NAKAHARA

G. KOTLIAR

D. HUSE

# RESISTIVE TRANSITION OF A TWO-DIMENSIONAL SUPERCONDUCTOR



Orderparameter  $\Delta e^{i\phi}$

$\triangle$  amplitude

$\phi$  phase

granular superconducting  
thin films

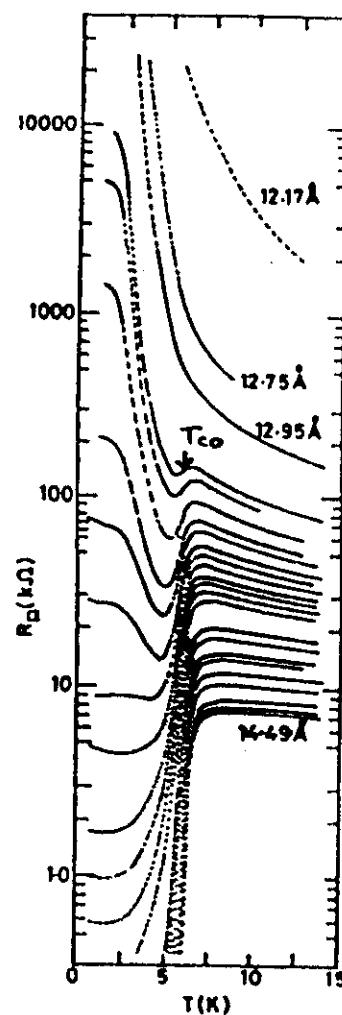


Fig. 2. Resistance per square  $R_0$  in  $\text{k}\Omega$  versus temperature for different amorphous Ga thin films. (After Ref. [8]).

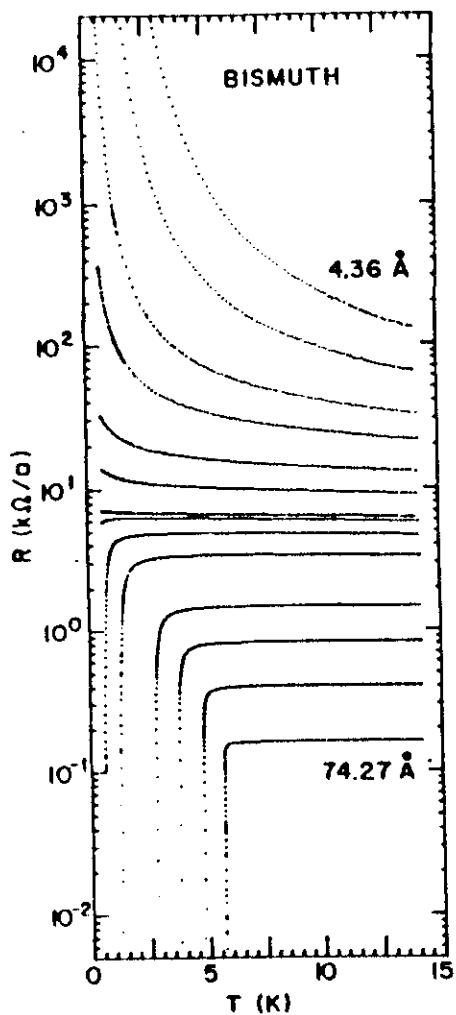
## Thesis Statement

For sufficiently thin homogeneously disordered films,

the true superconducting phase transition

(i.e., where LRO is established and the dc resistance is zero)

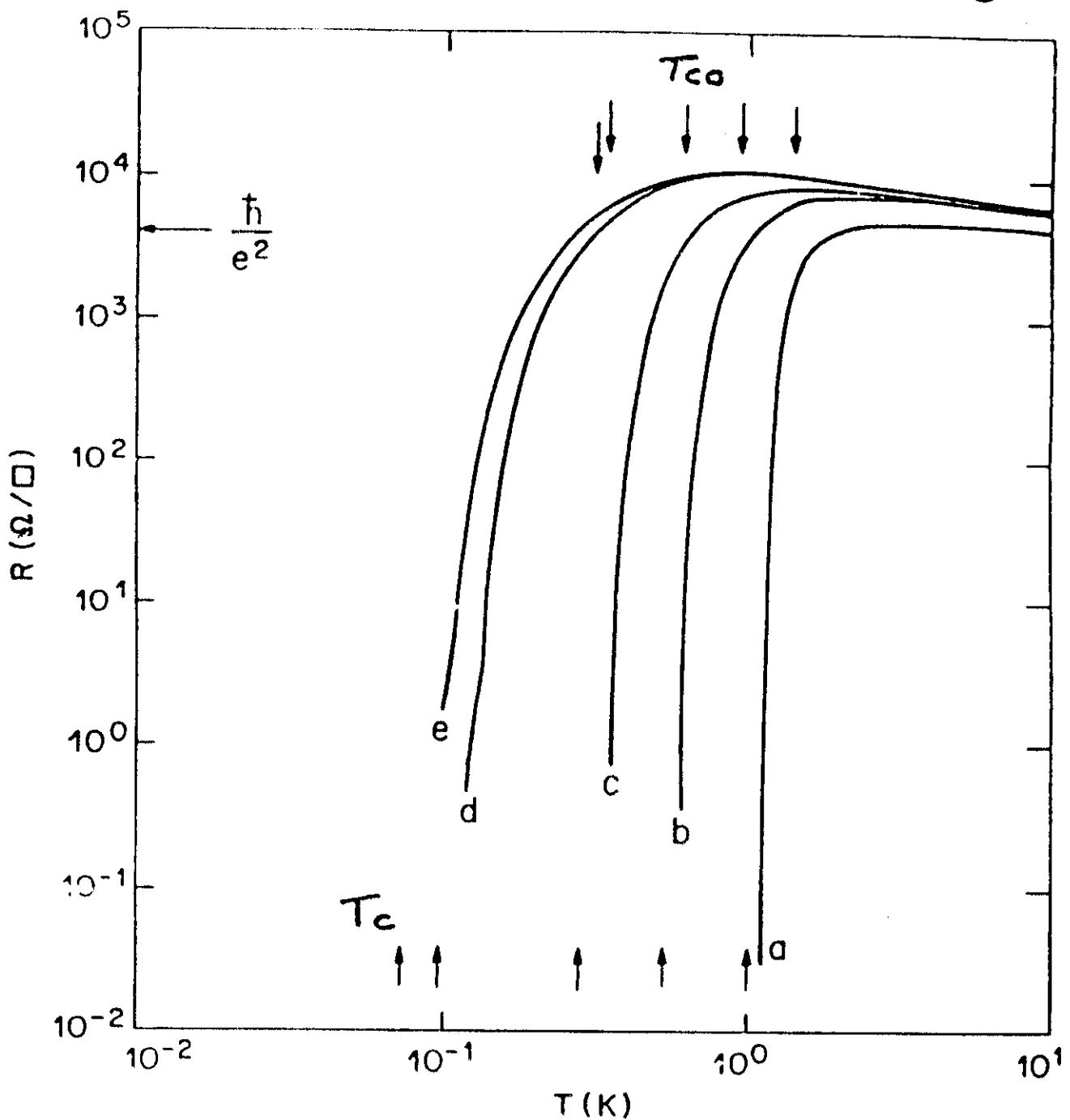
is dominated by phase fluctuations.



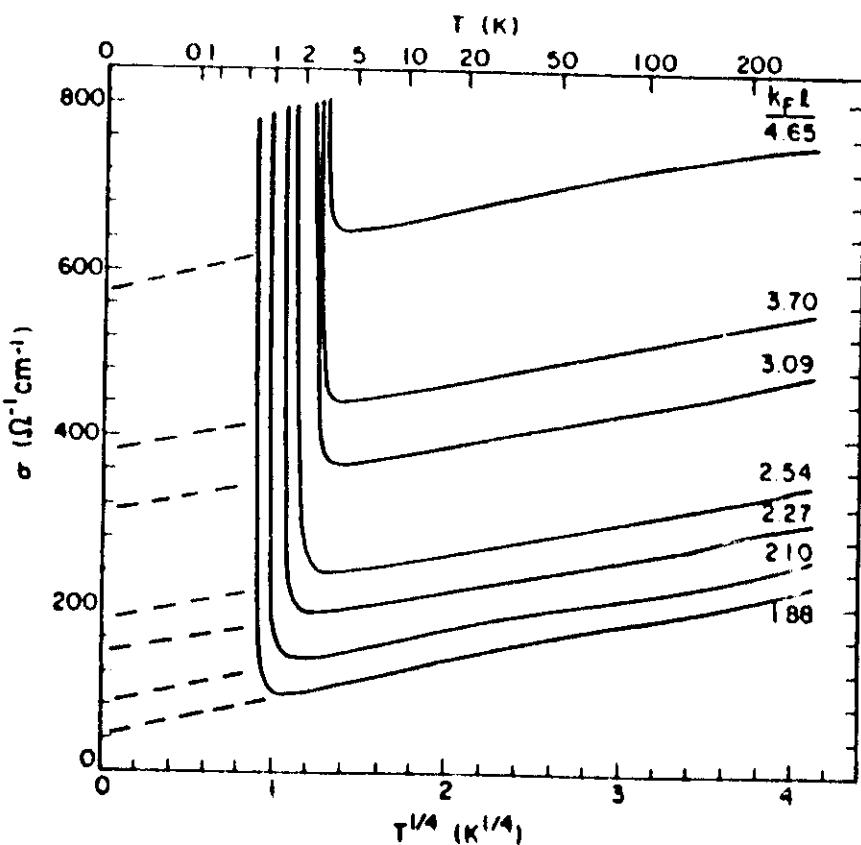
D.B. Haviland,  
Y. Liu  
A.M. Goldman  
PRL 62, 2130 (1989)

FIG. 1. Evolution of the temperature dependence of the sheet resistance  $R(T)$  with thickness for a Bi film deposited onto Ge. Fewer than half of the traces actually acquired are shown. Film thicknesses shown range from 4.36 to 74.27 Å.

$100 \text{ \AA}$  thick  $\text{InO}_x$   
films



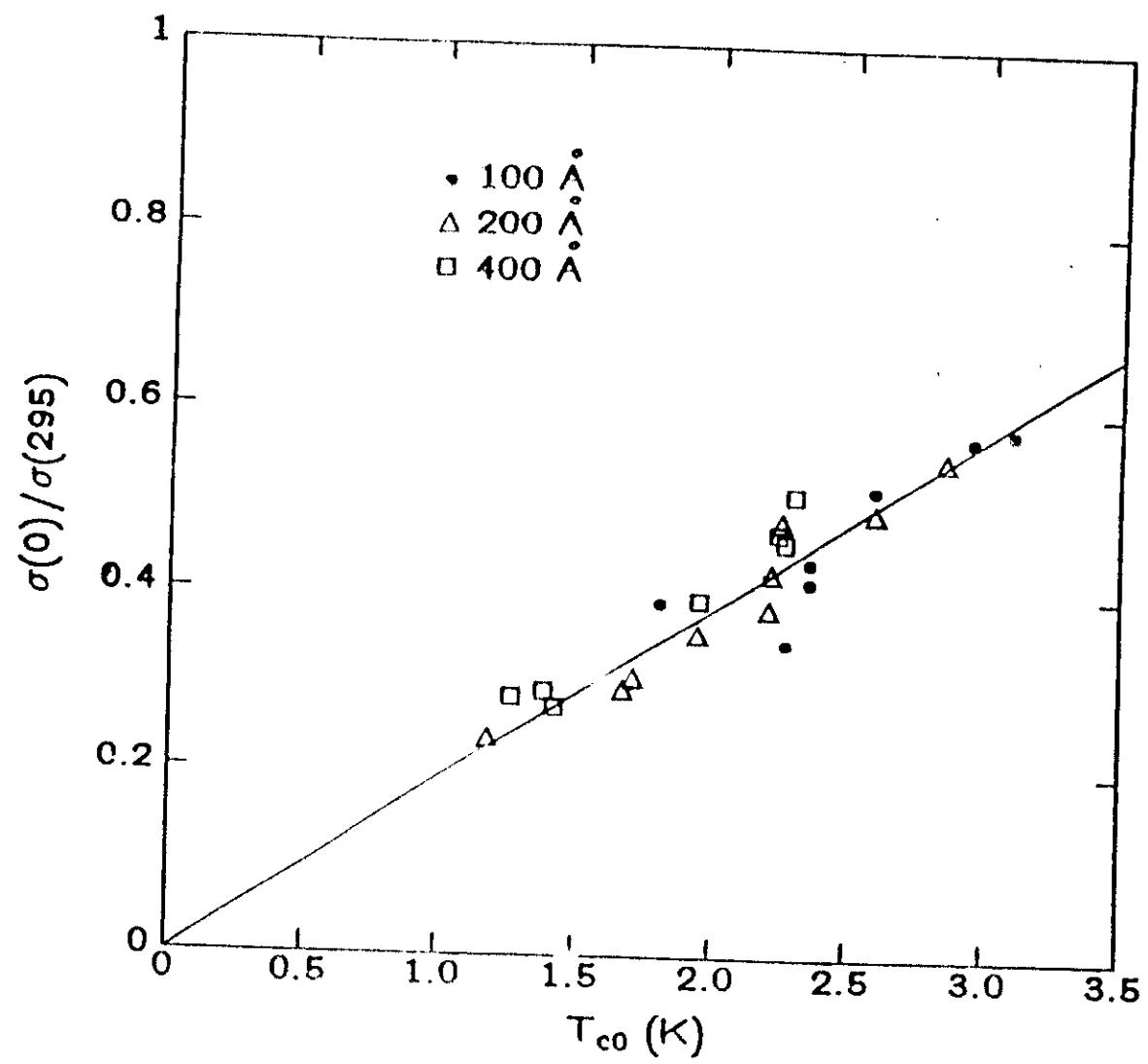
$$\sigma = \frac{e^2}{\hbar} \left( \frac{1}{\epsilon_L} + \frac{B}{\ell(T)} \right) ; \quad I(T) = A \left( \frac{\epsilon_F}{T} \right)^r$$



$$\frac{1}{\epsilon_L} \ll \frac{B}{\ell(T)}$$

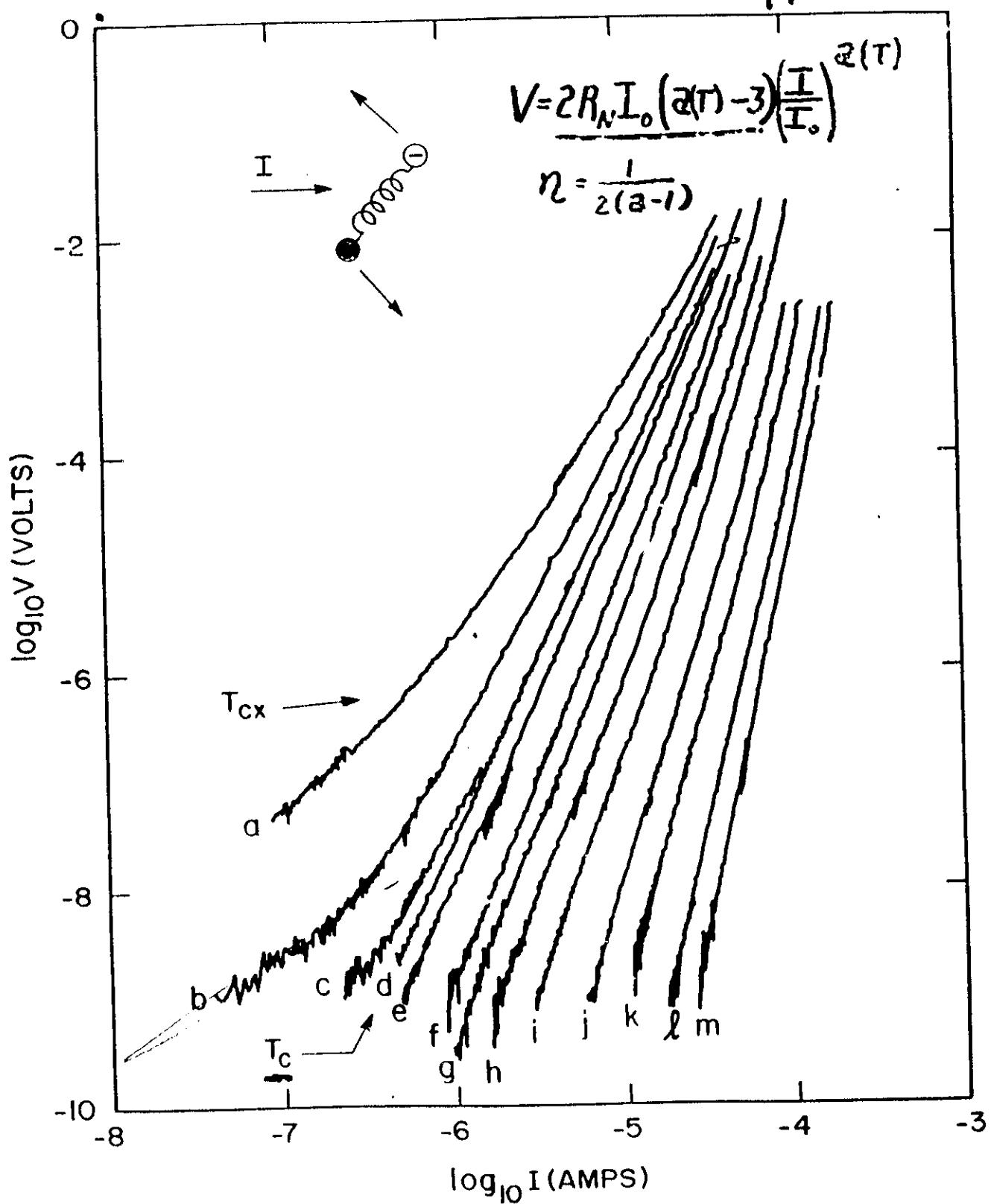
FIG. 2. Temperature dependence of the electrical conductivity of sample B at various stages of anneal with  $k_F L$  values given. Extrapolated dashed lines give  $\sigma(0)$ .

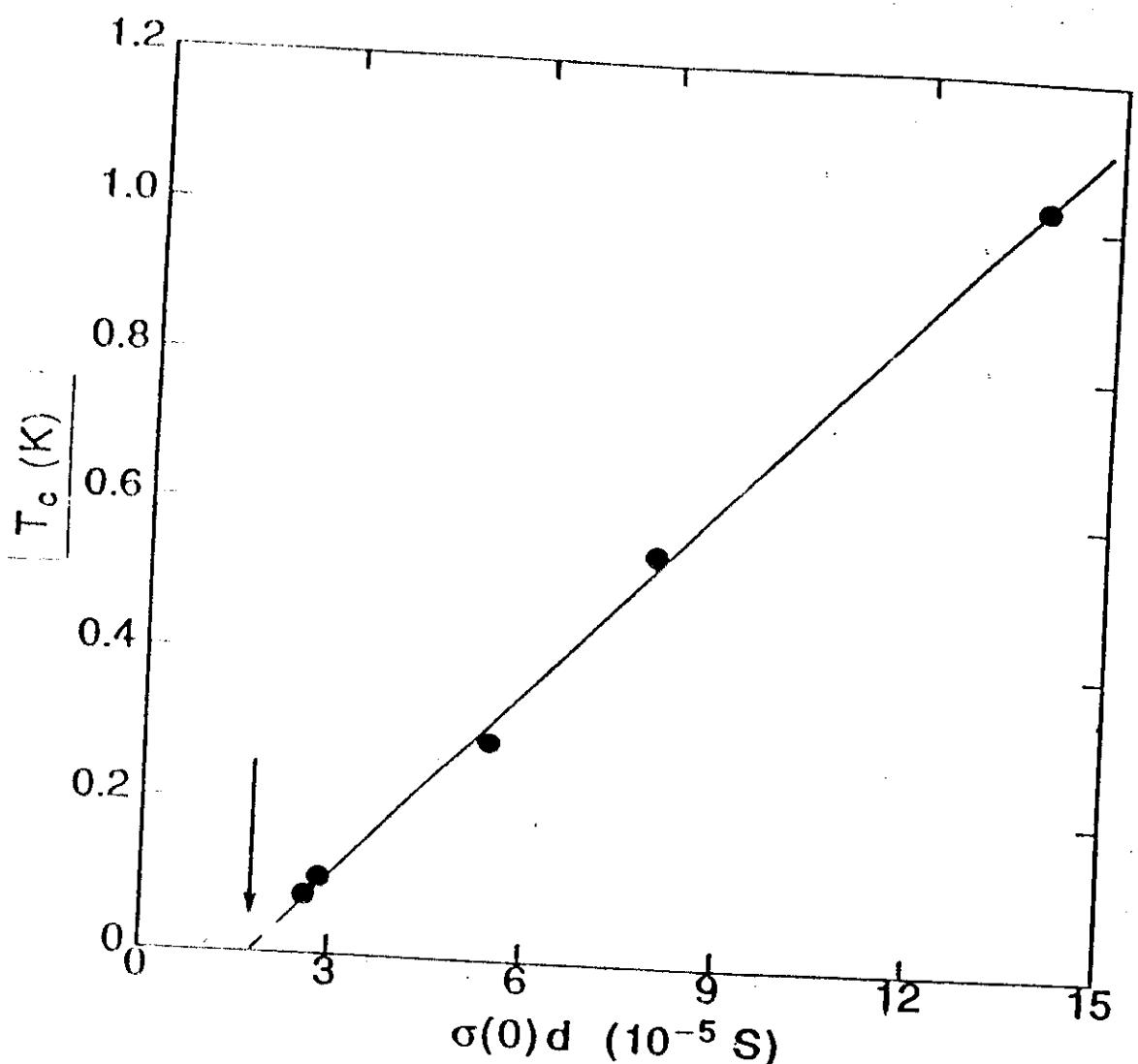
A.T. Froy & A.F. Hebard, PRB (1987).

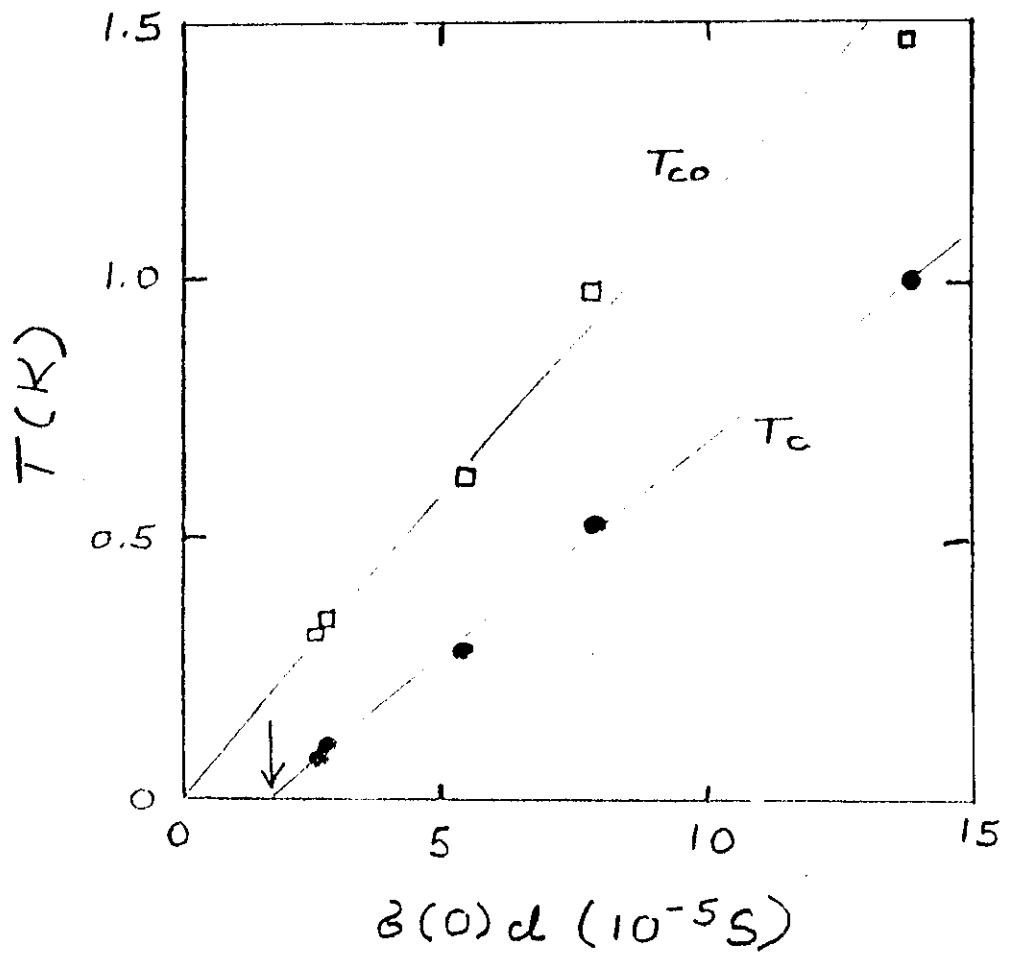


Determination of  $T_c$  - transition

- vortex - antivortex unbinding
- Kosterlitz - Thouless type

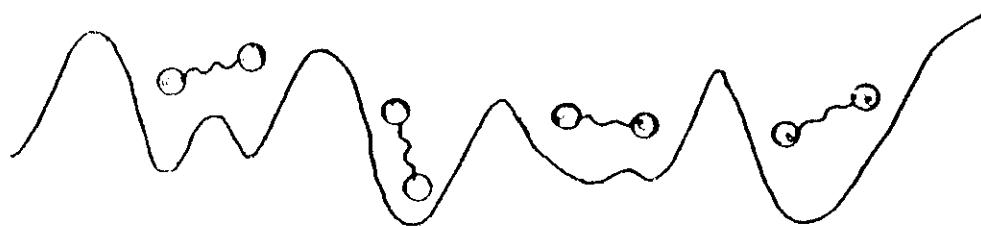




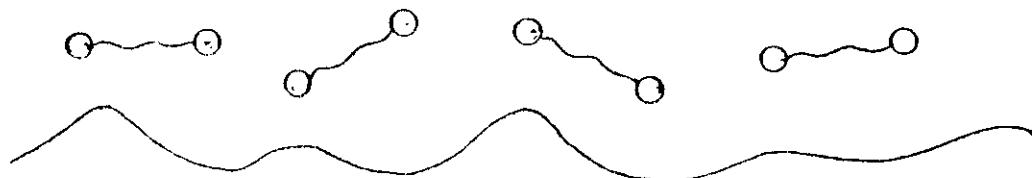


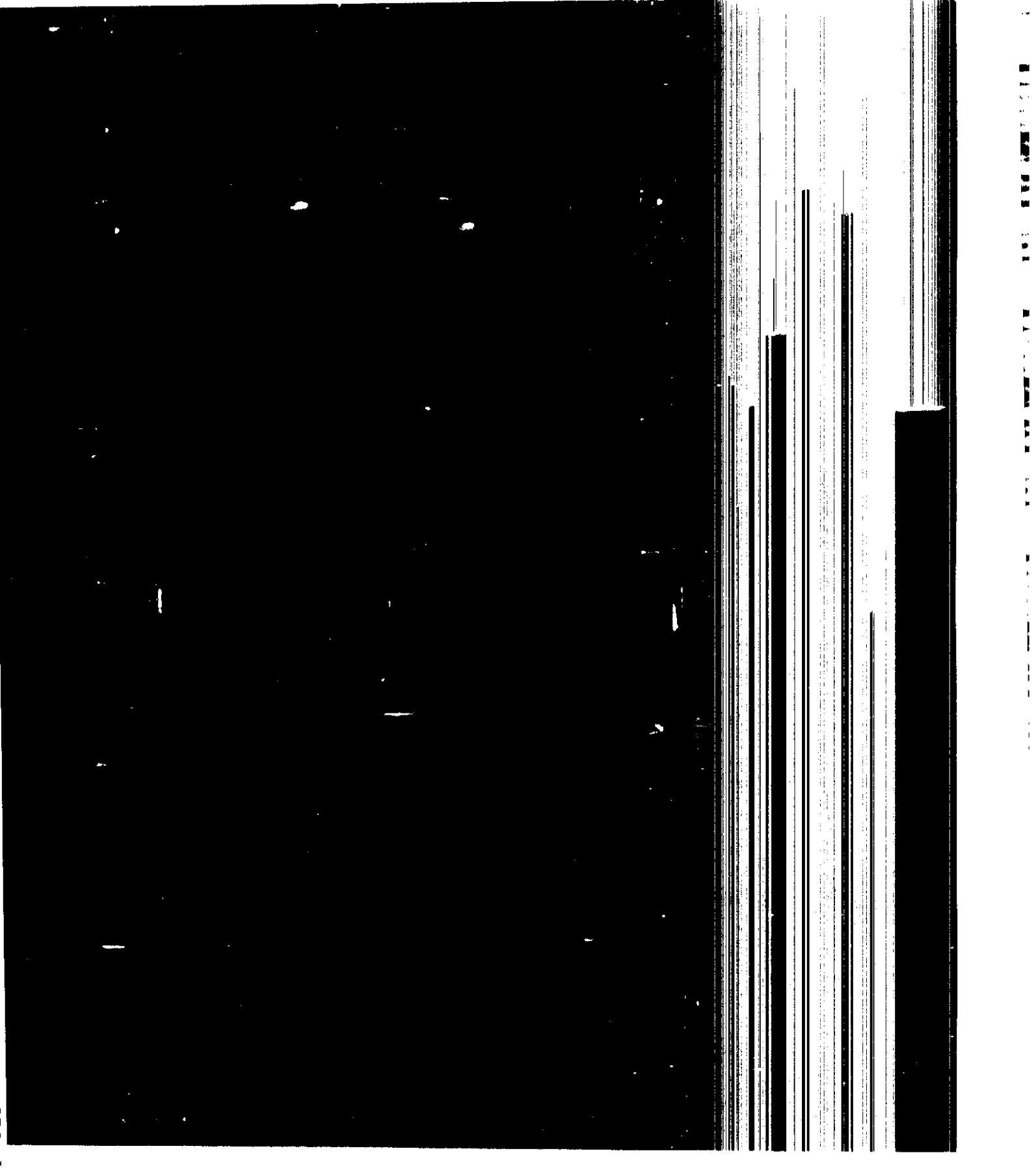
## **Cooper Pairs in a Random Potential**

- Insulating ( $\Delta > \Delta_c$ )



- Superconducting ( $\Delta < \Delta_c$ )





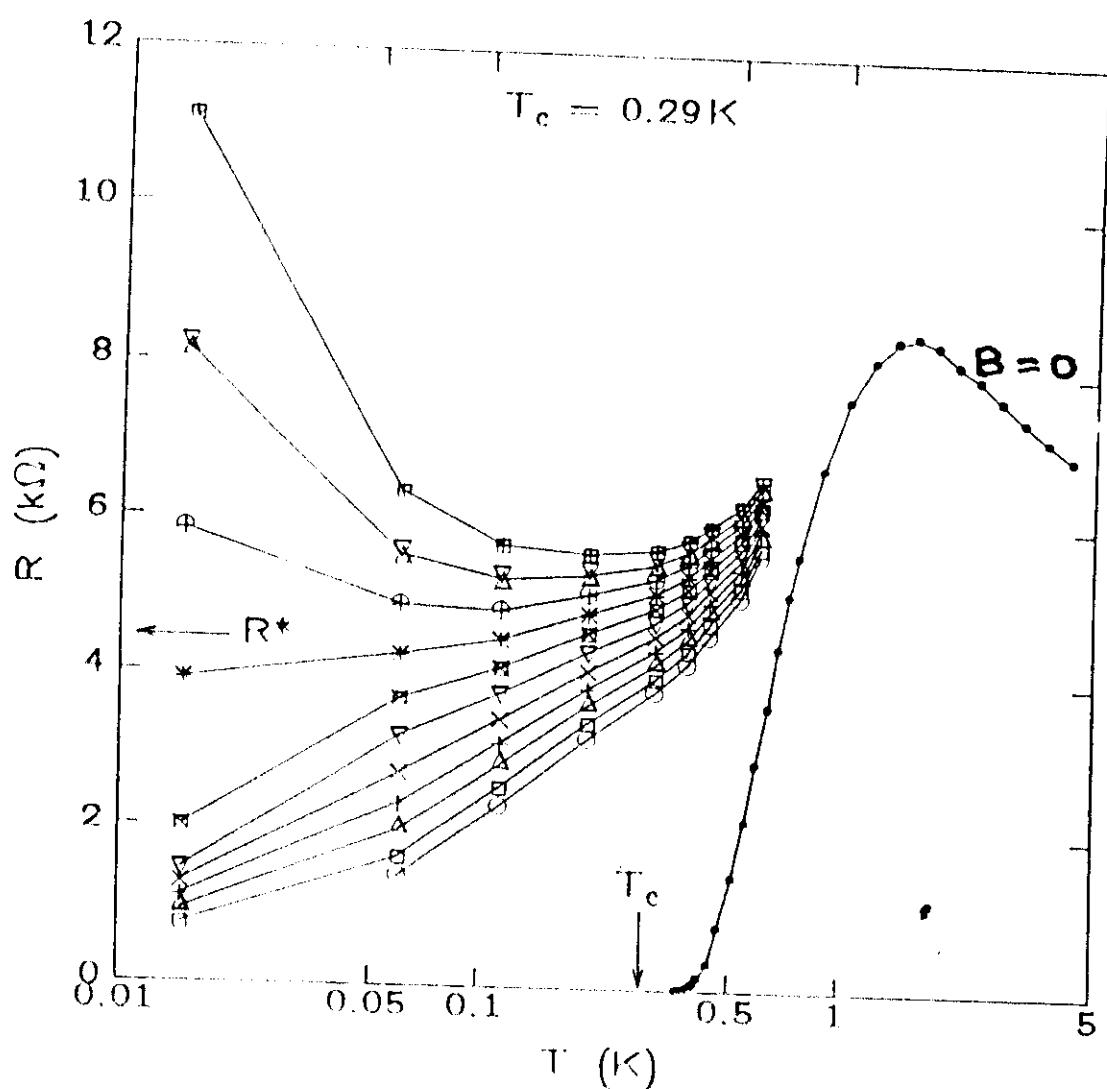
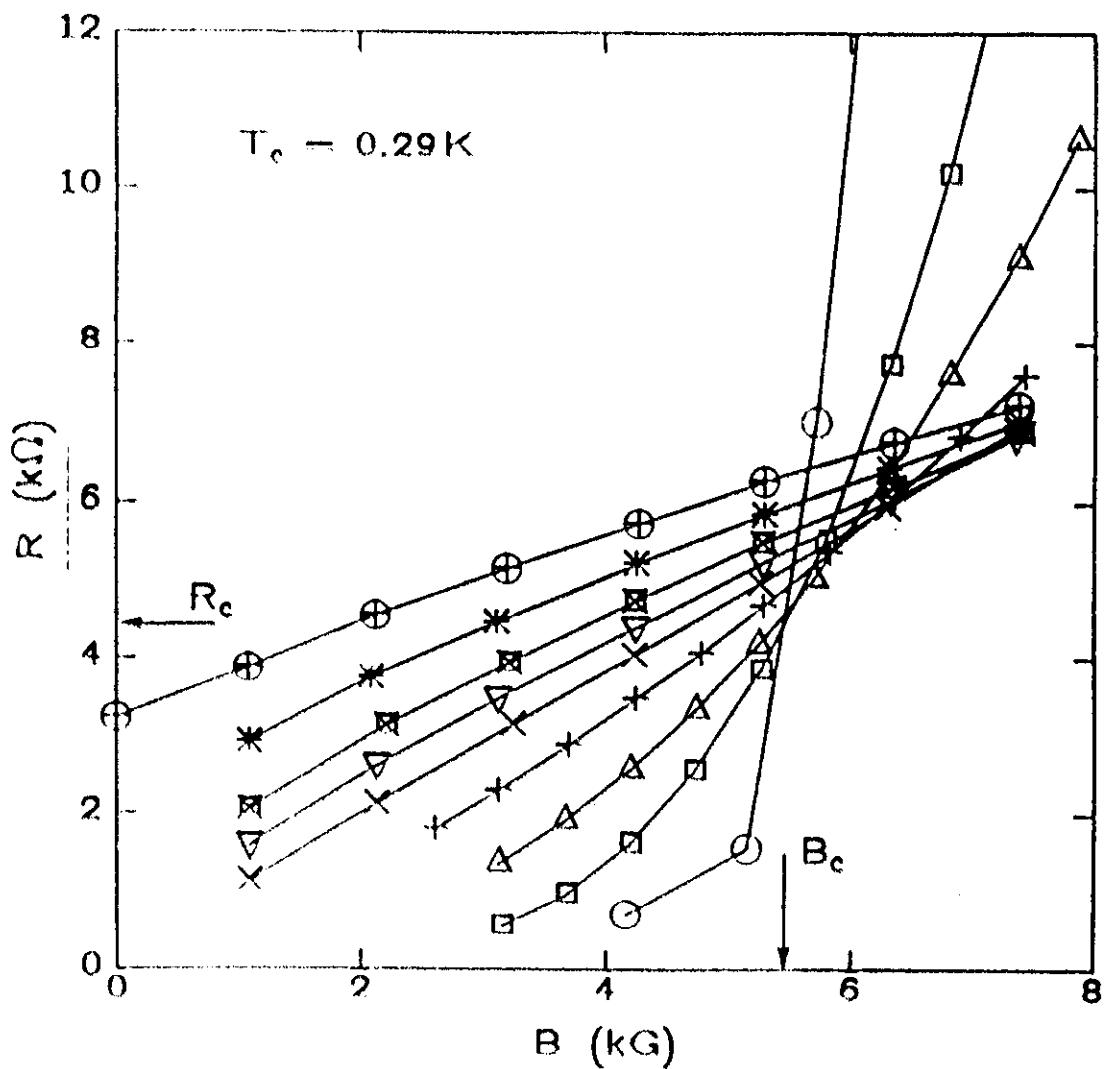
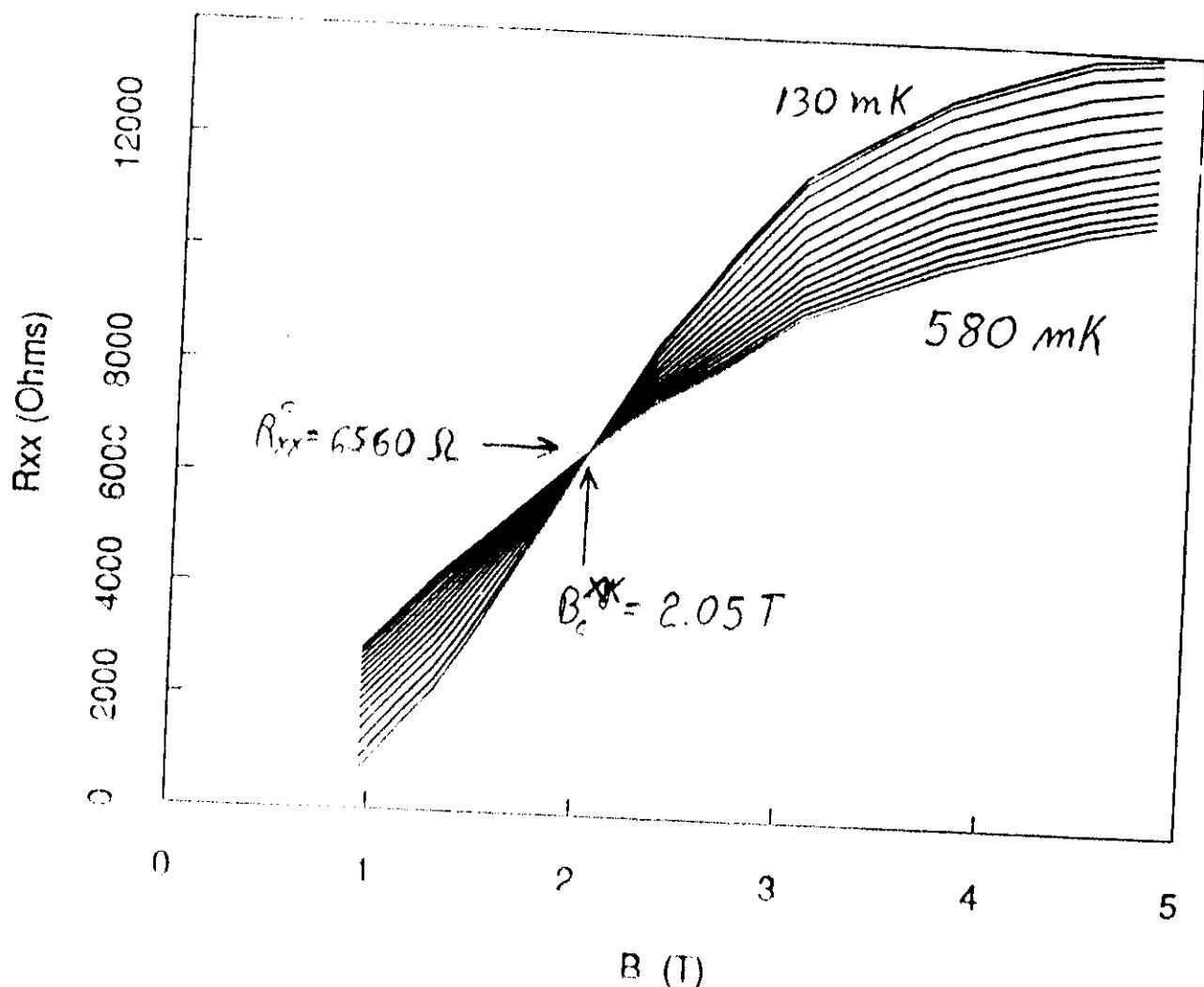


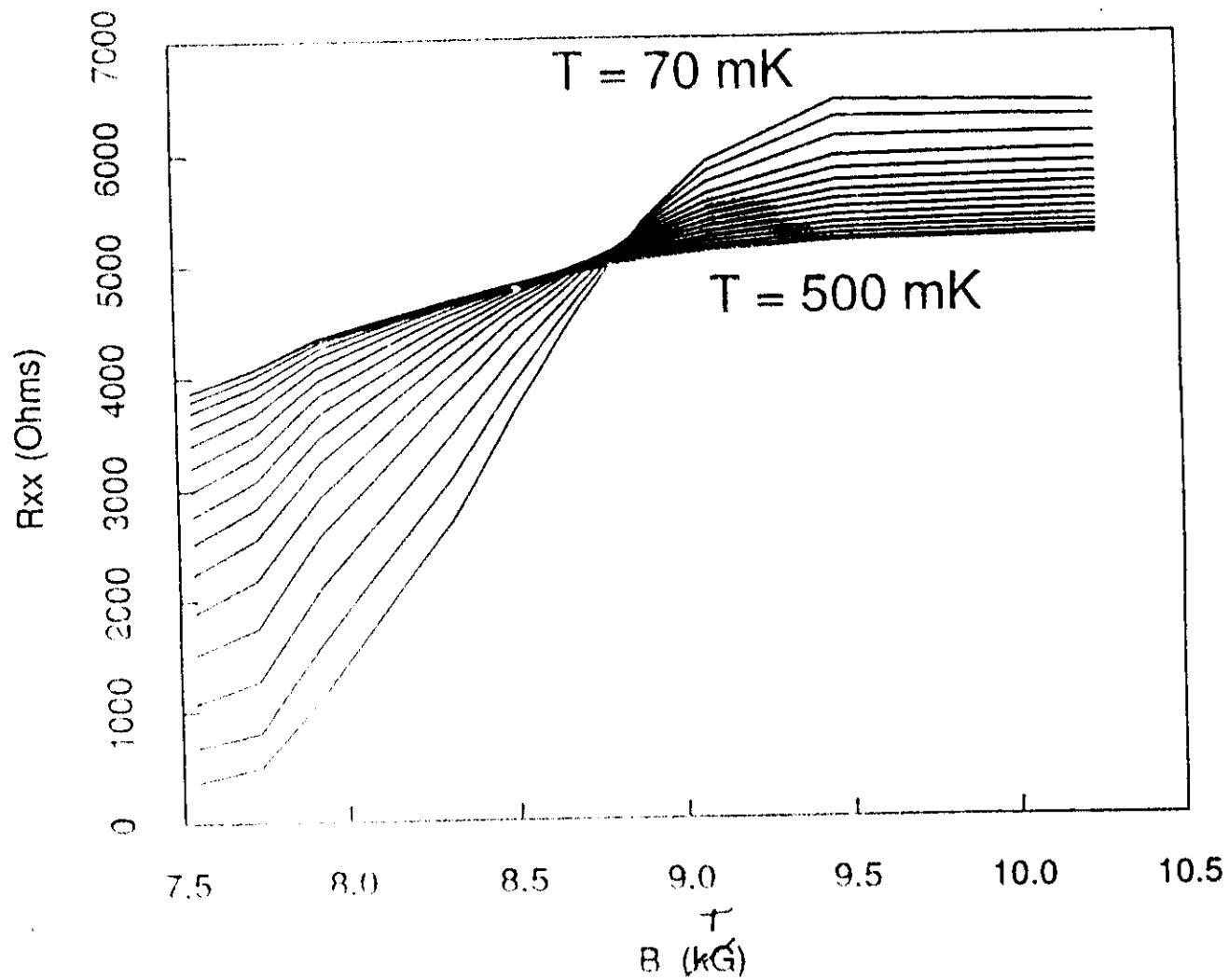
Figure 1



map8a:  $R_{xx}(B)$



map7a:  $R_{xx}(B)$



### Scaling Theory Exponents

- Scaling length  $\xi$  and frequency  $\Omega$ : ( $B=0, T=0$ )

$$\xi \sim (\Delta_c - \Delta)^{-\nu}, \quad \Omega \sim \xi^{-z}$$

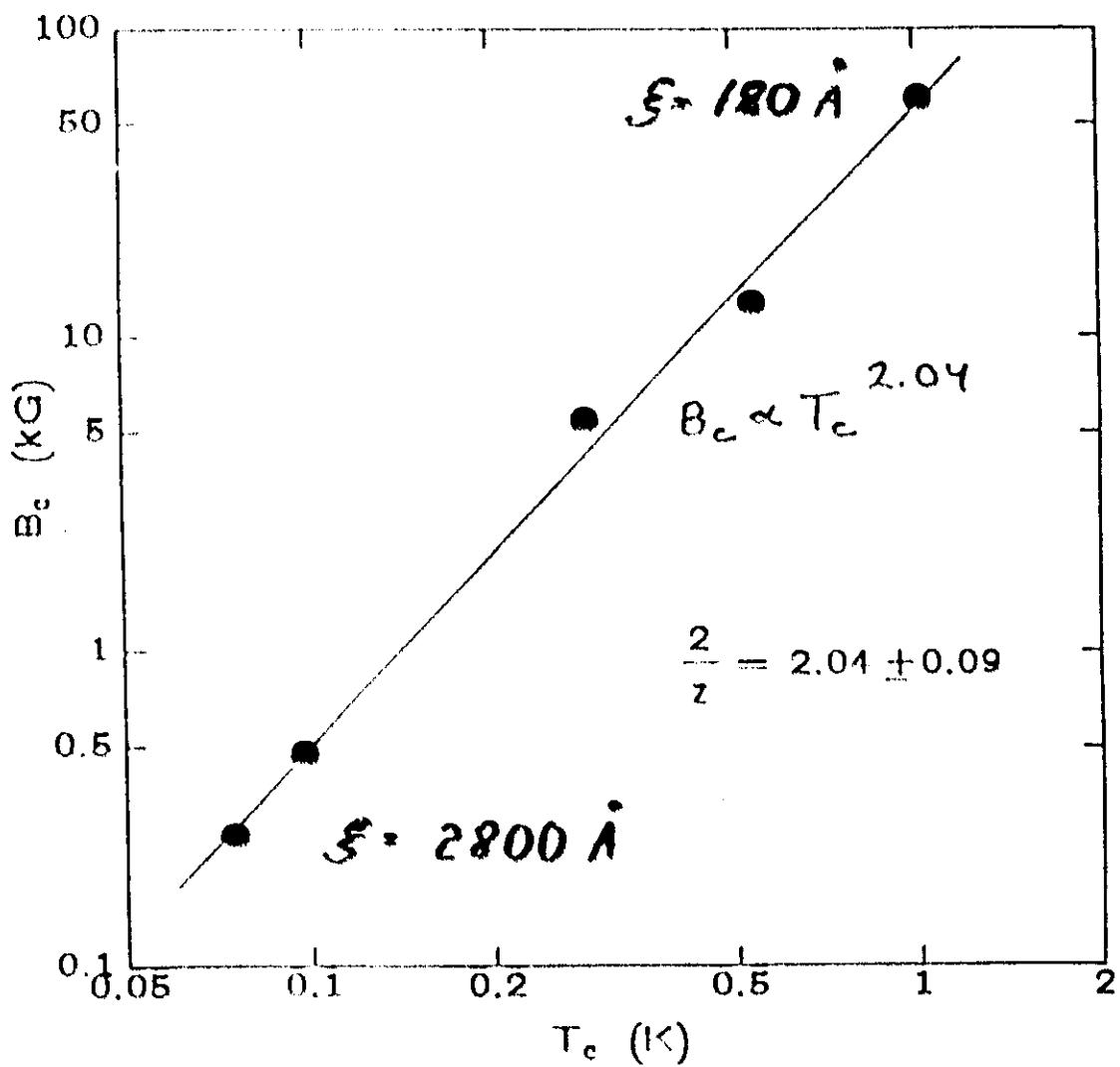
- Scaling dependence of  $T_c$  and  $B_c$ :

$$T_c \sim \Omega, \quad B_c \sim \xi^{-2}$$

- An experimental measurement of the dynamical exponent  $Z$  derives from

$$B_c \sim T_c^{2/z}$$

(The theoretical prediction is  $Z = 1$ )

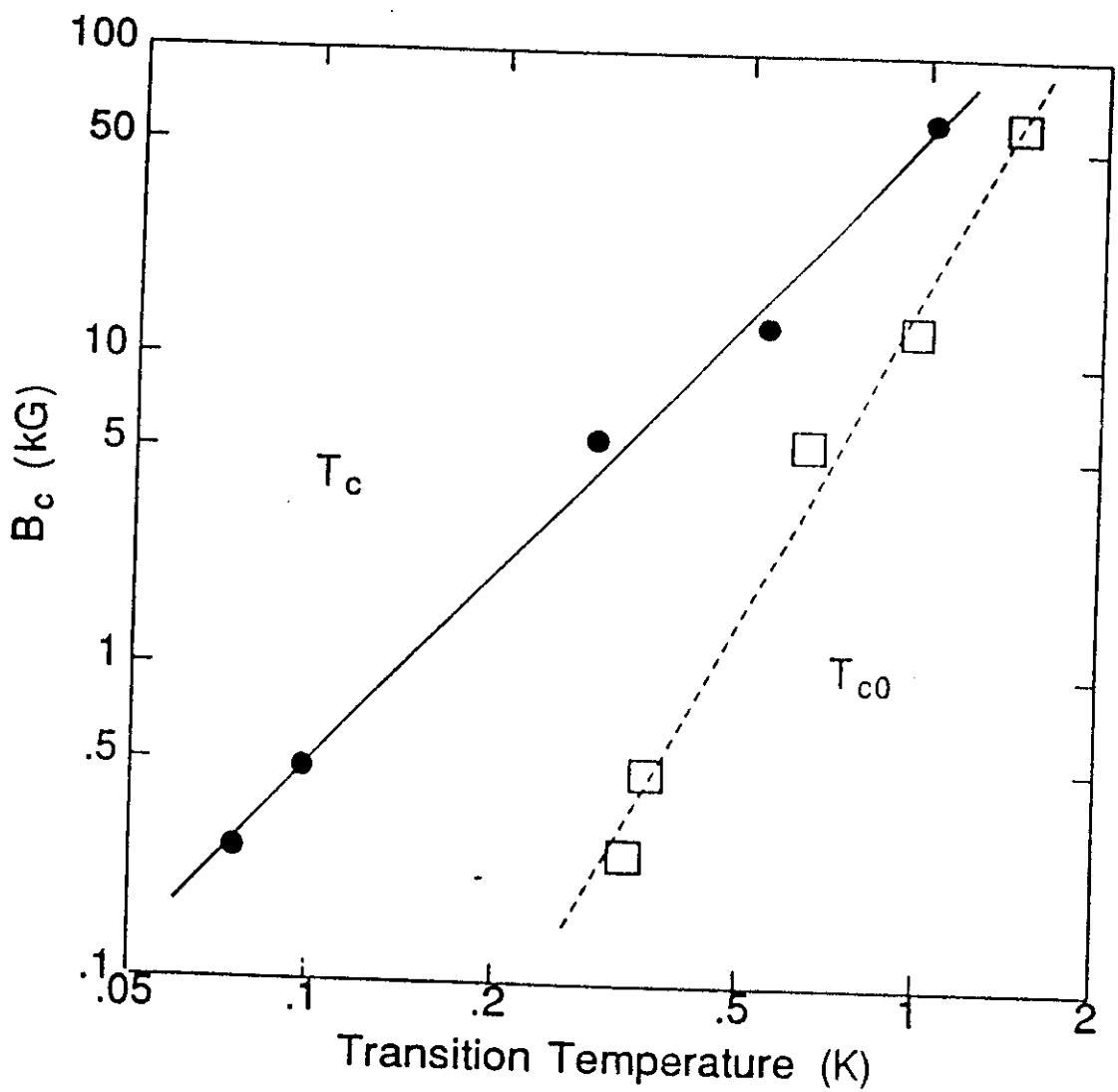


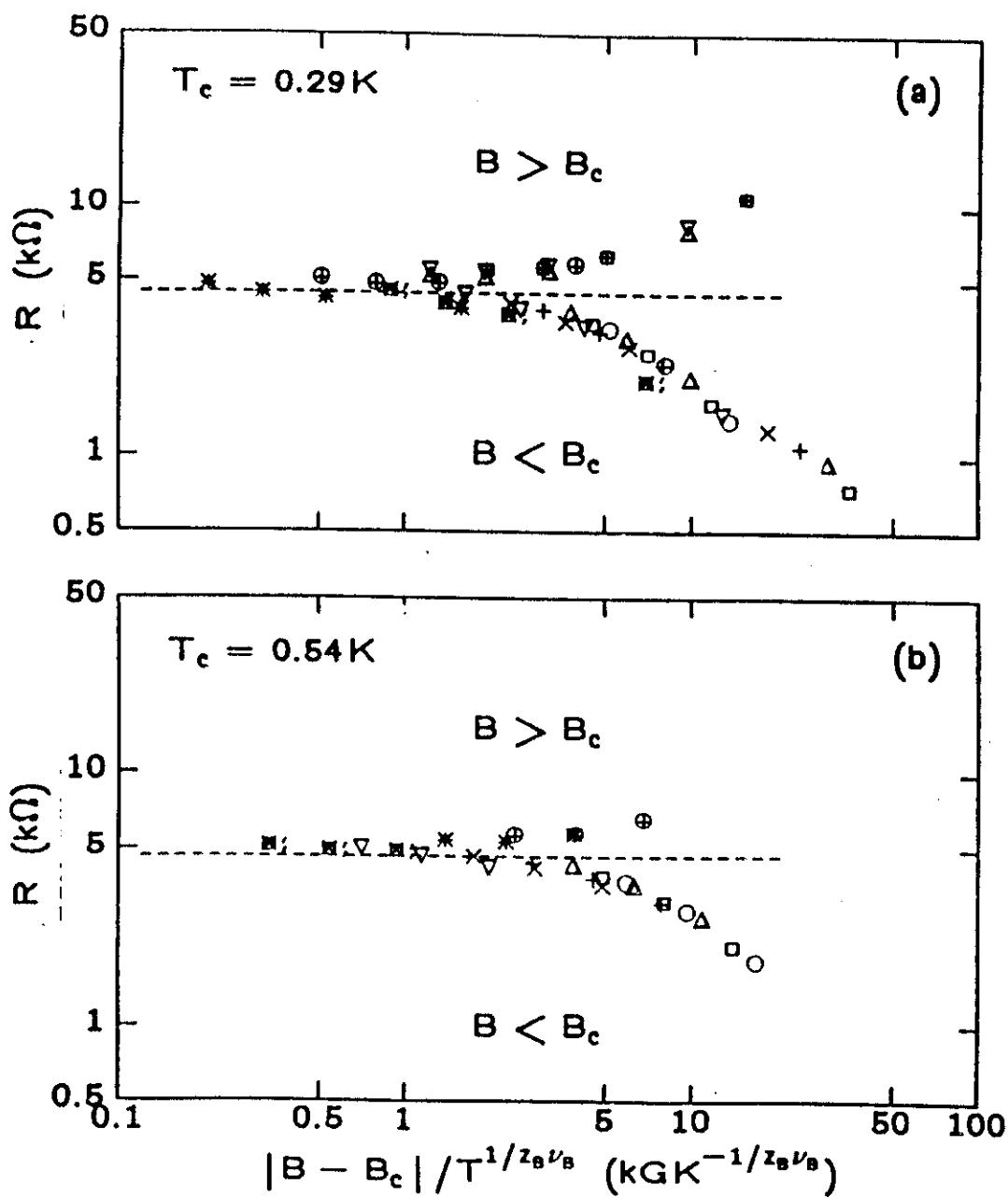
$$\xi_0 \approx \frac{v_F}{T_{co}}$$

$$B_c \sim \xi_0^{-2}$$

$$\Rightarrow T_{co} \sim B_c^2 ?$$

This is not true  
experimentally



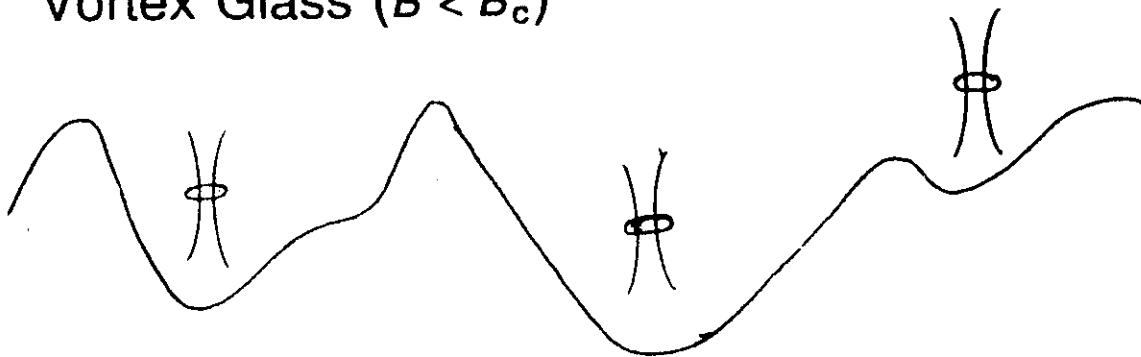


$$\nu_B = 1.3$$

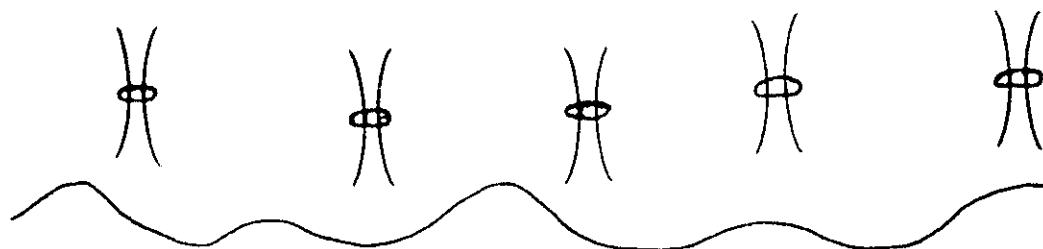
$$z_B = 1$$

## **Quantum Vortices in a Random Potential**

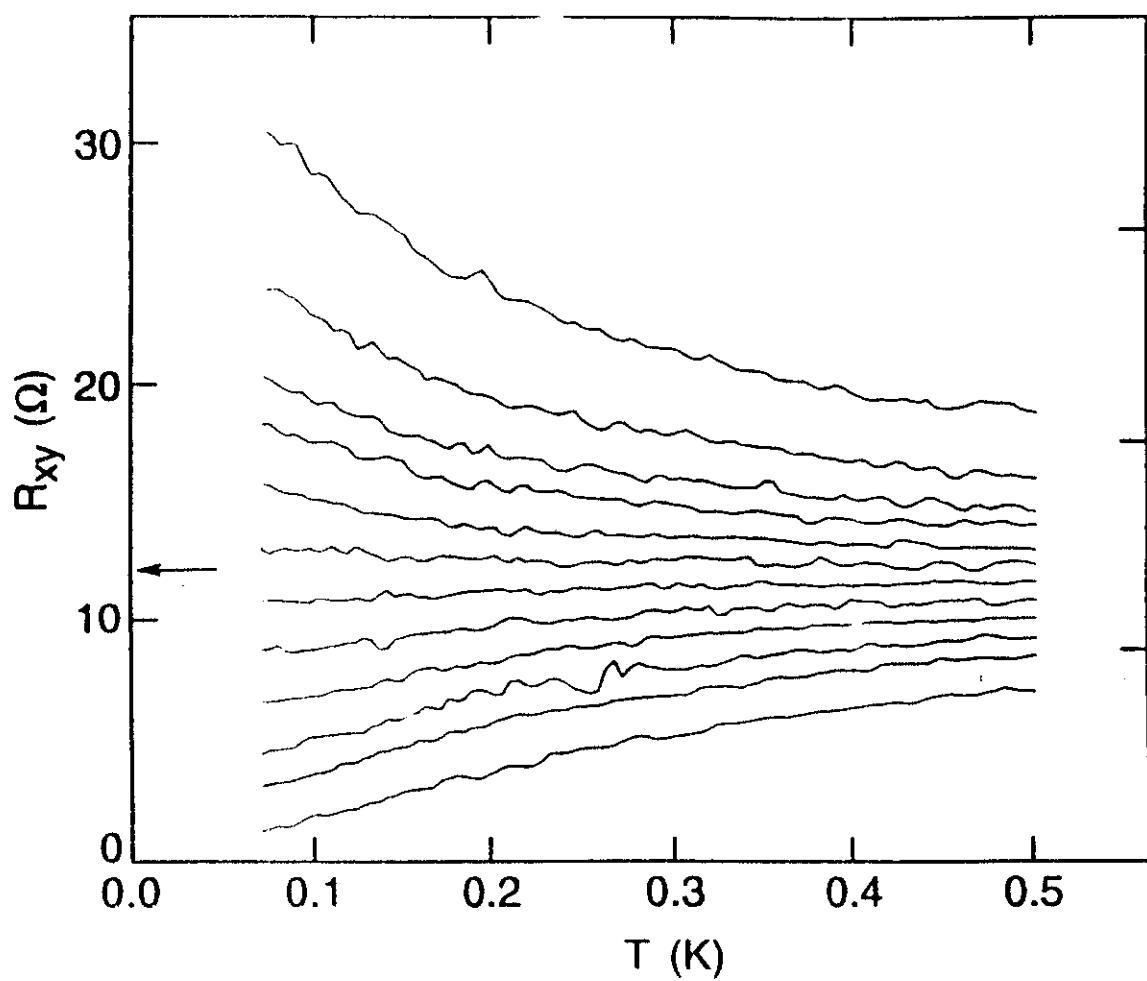
- Vortex Glass ( $B < B_c$ )



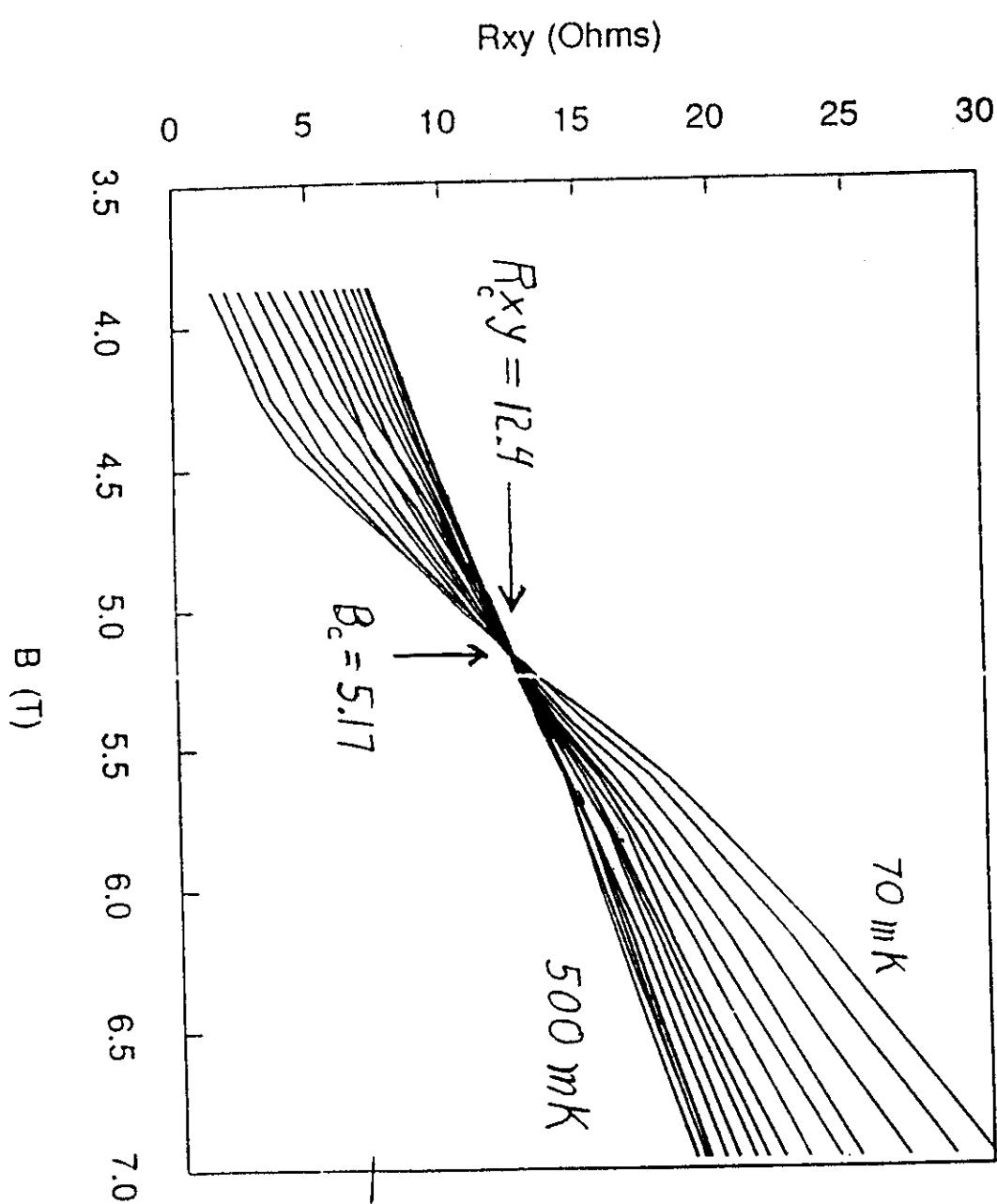
- Bose Insulator ( $B > B_c$ )

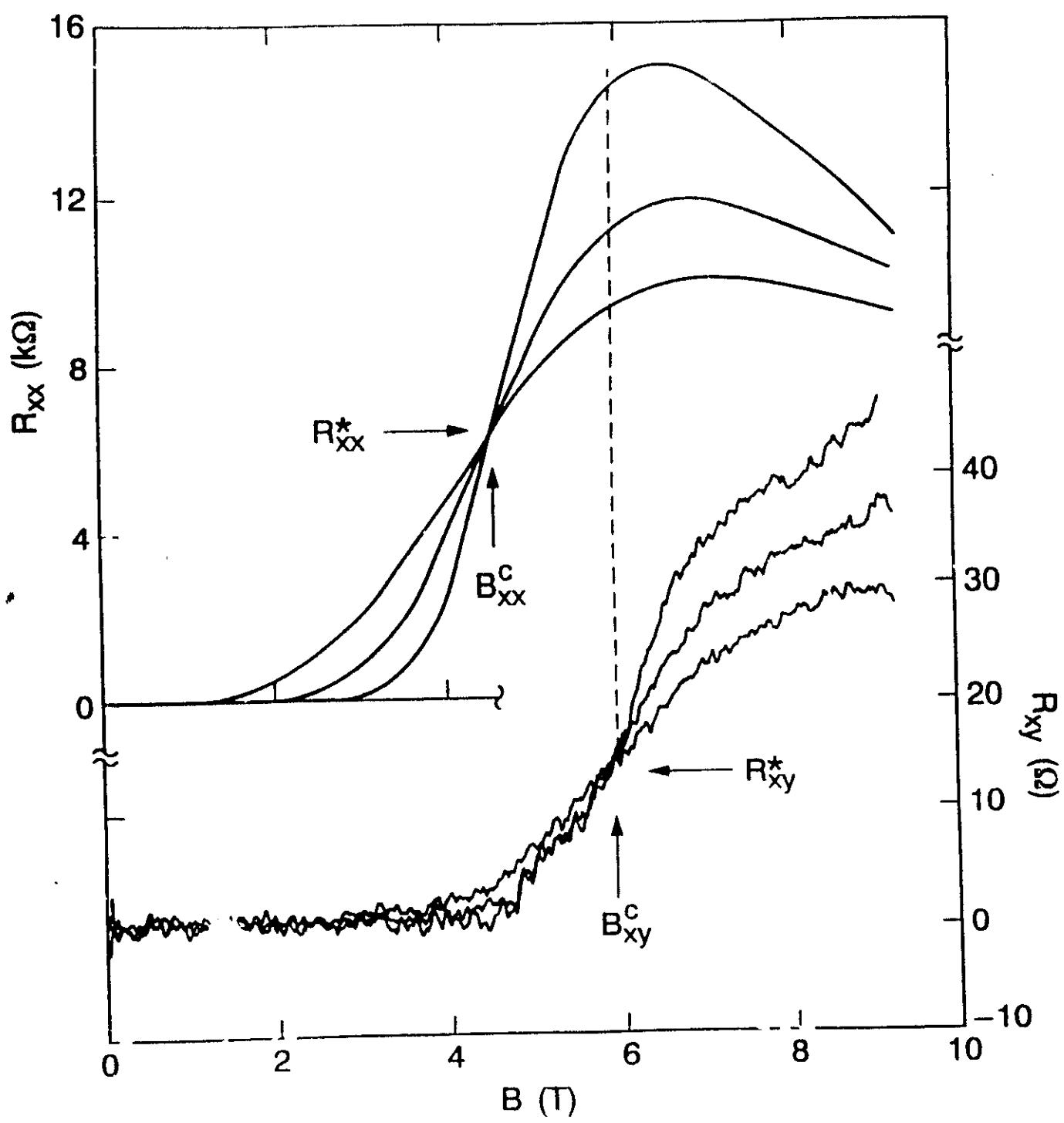


$$R_{xy} = \frac{B}{ne}$$

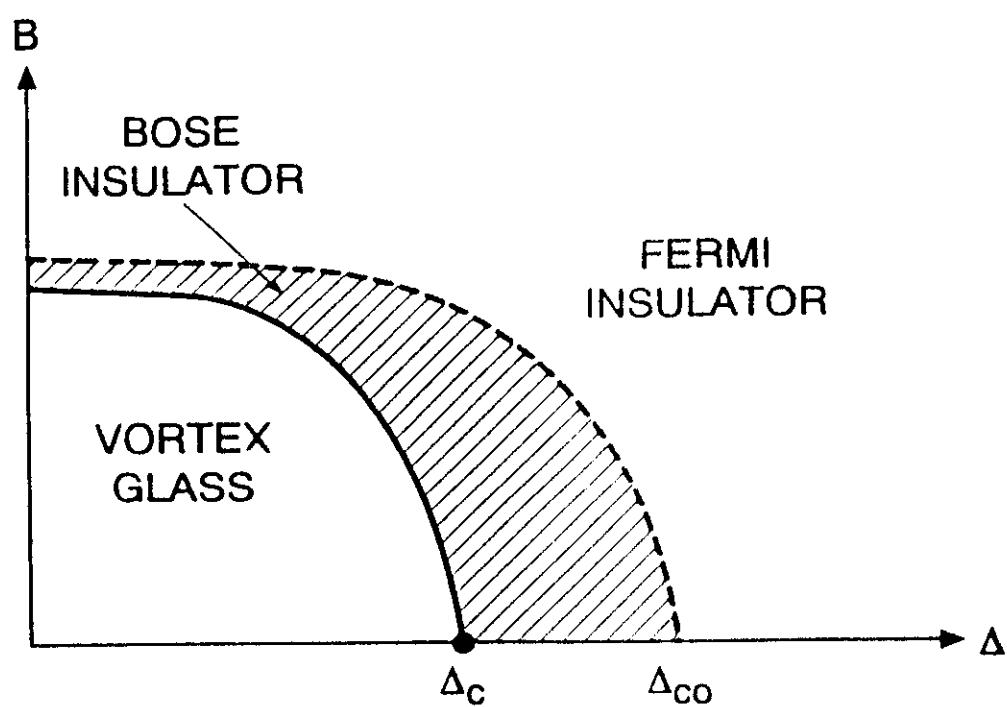


map7b:  $R_{xy}(B)$





(a)



(b)

